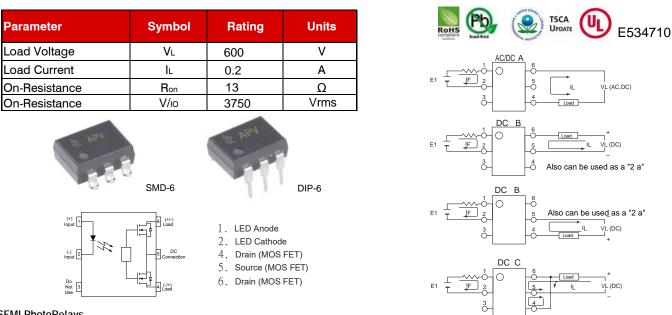
PSEM

1 Form A APV256AE_EH SMD-6/DIP-6 Load Voltage:600V Load Current:200mA



APSEMI PhotoRelays

®

APSEMI Photorelays are the most reliable, technically advanced logic-to-power interface devices. Their basic function is to take a low current signal from a microprocessor to control the switching of both AC and DC loads, while providing an isolation barrier between logic and power. While this function is common to all relays, Photorelays provide distinct advantages over their mechanical counterparts including:

- Long life (No limit on mechanical and electrical
- lifetime)Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)

- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact AC or DC load
- switching
- Small package size

Immunity to EMI or RFI

Applications

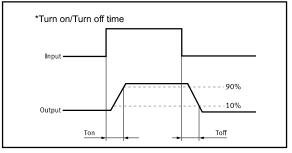
These advantages make APSEI Photorelays the ideal choice for:

- Telecom/Datacom switching •
- Multiplexers •
- Meter reading systems
- Data acquisition
- Medical equipment •
- Battery monitoring •
- I/O Sub-Systems •

- Home/Safety security systems
- Process Control
- **Energy Management**
- Reed Relay EMR Replacement
- Programmable Controllers

TPYES

Category	Output Rating		Paakaga	Part No.	Packing Quantity
	Load Voltage	Load Current	Package	Fall NO.	Packing Quantity
AC/DC	600V 0.2A	0.04	DIP-6	APV256AE	50pcs /tube
		0.2A	SMD-6	APV256AEH	1000pcs /reel



Robotics Aerospace

1 Form A APV256AE_EH SMD-6/DIP-6 Load Voltage:600V Load Current:200mA

RATING

®

Absolute maximum ratings

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Parameter		Symbol	Min.	Max.	Units	Note
Storage Temperature	Τ _S	-55	125	°C		
Operating Temperature		TA	-40	85	°C	
Junction Temperature		Тյ		125	°C	
Lead Soldering Cycle	Temperature			260	°C	
	Time			10	sec	
Input Current	Average	I _F		25	mA	
	Surge			50	mA	
	Transient			1000	mA	
Reversed Input Voltage		V _R		5	V	
Input Power Dissipation		P _{IN}		40	mW	
Output Power	Connection A	Po		640	mW	
Dissipation	Connection B			640	mW	
Average Output Current	Connection A	IO		0.2	А	
$(T_A = 25^{\circ}C, T_C \le 100^{\circ}C)$	Connection B	_		0.4	А	
Output Voltage	Connection A	Vo	- 600	600	V	1
(T _A =25°C)	Connection B		0	600	V	
ESD Human Body Model: MIL-STD-883 Method 3015.7				4	kV	
Solder Reflow Temperatu	See Lead	Free IR Pro	file			

Recommended operating conditions Please use under recommended operating conditions to obtain expected characteristics.

Parameter	Symbol	Min.	Max.	Units	Note
Input Current (ON)	I _{F(ON)}	3	20	mA	
Input Voltage (OFF)	V _{F(OFF)}	0	0.8	V	
Operating Temperature	T _A	-40	+85	°C	

Electrical characteristics

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Electrical Specifications (DC)

Over recommended operating $T_A = -40^{\circ}$ C to 85°C, $I_F = 5$ mA to 10mA, unless otherwise specified.

Parameter Output Withstand Voltage		Sym.	Min.	Тур.	Max.	Units	Conditions	Fig.	Note
		V _{O(OFF)} 600	600	650		V	V _F =0.8V, I _O =250μA, T _A =25°C		
			550			V	V _F =0.8V, I _O =250μA		
Output On-Resistance	Connection A	R _(ON)		13	16	Ω	I _F =5mA, I _O =0.4A, Pulse ≤30ms, T _A =25°C	3 10	- 6
	Connection B	R _(ON)		2.5	4	Ω	I _F =5mA, I _O =0.4A, Pulse ≤30ms, T _A =25°C	11	6
Output Leakage Current		I _{O(OFF)}		0.001	0.1	μΑ	V _F =0.8V, V _O =600V, T _A =25°C	5	-
					1	μA	V _F =0.8V, V _O =550V	4	-
Output Off-Capa	acitance	C _(OFF)		500		рF	V _F =0.8V, V _O =0V, f=1MHz	6	-
Output Offset Voltage		V _(OS)		1		μV	I _F =5mA, I _O =0mA		
Input Reverse Breakdown Voltage		VR	5			V	I _R =10μΑ		
Input Forward Voltage		VF	1.1	1.3	1.7	V	I _F =5mA	7,8	-

Switching Specifications (AC)

Over recommended operating $T_A = -40^{\circ}$ C to 85°C, $I_F = 5$ mA to 10mA, unless otherwise specified.

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions	Fig.	Note
Turn On Time	T _{ON}		0.7	2.5	ms	I _F =5mA, I _O =0.4A, T _A =25°C	12,16	
				5.0	ms	I _F =5mA, I _O =0.4A	13,16	
			0.4	1.5	ms	I _F =10mA, I _O =0.4A, T _A =25°C		
				3.0	ms	I _F =10mA, I _O =0.4A	13,16	
Turn Off Time	T _{OFF}		0.07 0.5 ms I _F =5mA, I _O =0.4A, T _A =25°C		I _F =5mA, I _O =0.4A, T _A =25°C	14,16		
				1	ms	I _F =5mA, I _O =0.4A	15,16	
			0.06	0.2	ms	I _F =10mA, I _O =0.4A, T _A =25°C	14,16	
				0.5	ms	I _F =10mA, I _O =0.4A	15,16	
Output Transient Rejection	dV _O /dt	1	7		kV/μs	$\label{eq:dv_O} \begin{split} \Delta V_O = & 600V, \ R_M \geq 1 M \Omega, \\ C_M = & 1000 \ pF, \ T_A = & 25^\circ C \end{split}$	17	5
Input-Output Transient Rejection	dV _{I-O} /dt	1	20		kV/μs	V _{DD} =5V, ΔV _{I-O} =1000V, R _L =1kΩ, C _L =25pF, T _A =25°C	18	5

APSEMI

Engineering Data

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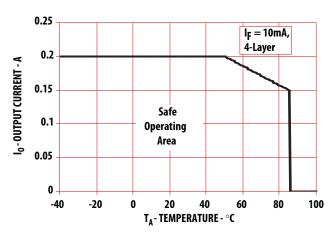


Figure 1. Maximum Output Current Rating vs Ambient Temperature (AC/DC Connection)

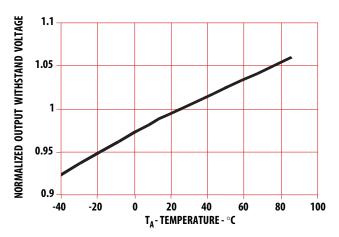


Figure 3. Normalized Typical Outupt Withstand Voltage vs Temperature

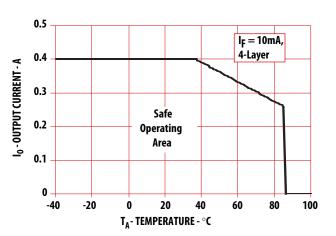


Figure 2. Maximum Output Current Rating vs Ambient Temperature (DC Connection)

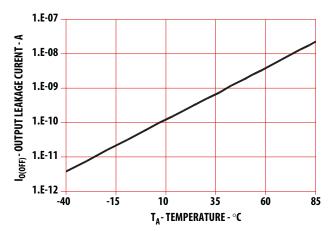
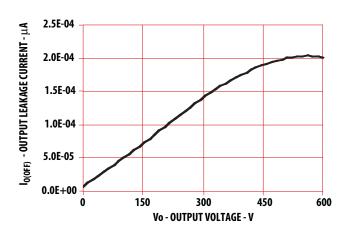
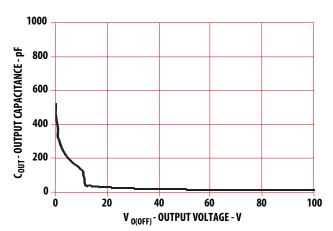
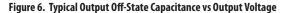


Figure 4. Typical Output Leakage Current vs Ambient Temperature



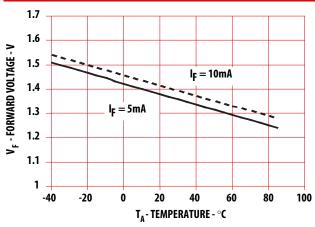


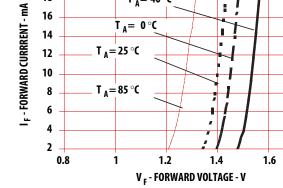




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T_A=-40 °C

 $T_A = 0 \circ C$

T_A=25 °C

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1.8

20 18

16

14

12



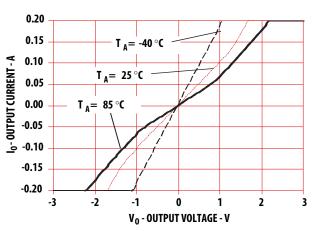
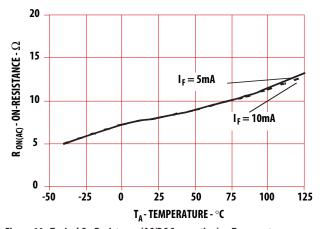


Figure 9. Typical Output Current vs Output Voltage







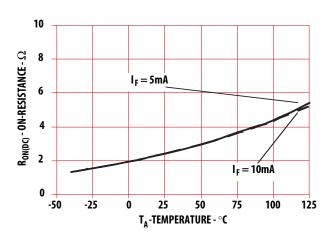


Figure 11. Typical On Resistance (DC Connection) vs Temperature

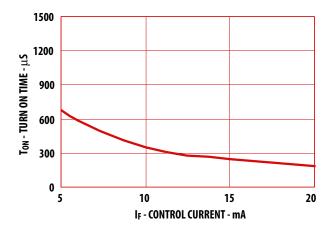
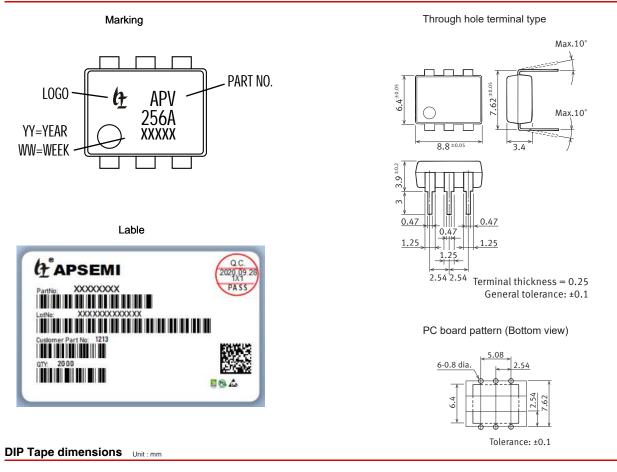


Figure 12. Typical Turn On Time vs Input Current

Dimensions and DIP-6 Package Unit: mm

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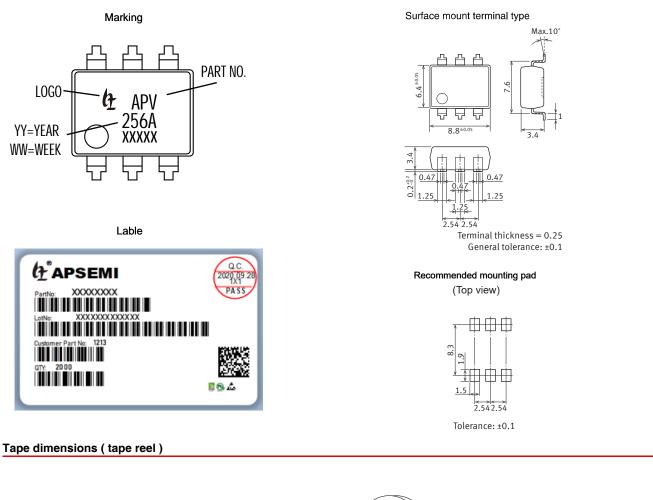
Devices are packaged in a tube so that pin No. 1 is on the stopper B side. Observe correct orientation when mounting them on PC boards.

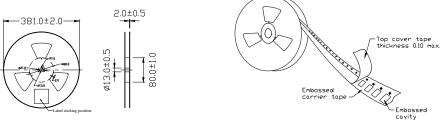


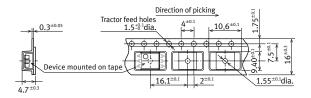
APSEM SMD-6/I

Dimensions and SMD-6 Package Unit: mm

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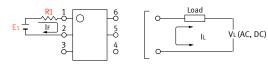






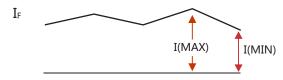
Using Methods

Examples of resistance value to control LED forward current (IF=5mA)



E1	R1 (Approx)
3.3V	300 Ω
5.0V	600 Ω
12V	1.9KΩ
24V	4.1K Ω

LED forward current must be more than 5mA , at I(MIN) ,and less than 30mA , at I(MAX).



Recommended Operating Conditions

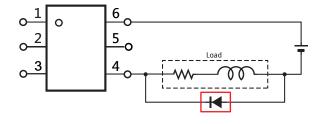
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

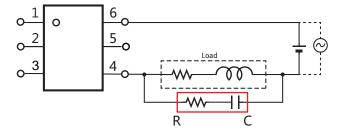
Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	١ _F	5.0	7.0	30	mA

Protection Circuit

Clamp diode is connected in parallel with the load. Absorb capacity with external diode.

CR Snubber is connected in parallel with the load. Absorb capacity with buffer capacity.





When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective. Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.

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